Resonantly photopumped lasing and its switching behavior in a photonic crystal nanolaser

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A GaInAsP photonic crystal nanolaser was operated by resonant optical pumping in which the effective cavity area was selectively excited. The laser mode intensity was markedly enhanced when the pump wavelength was tuned to a higher-order cavity mode, and room-temperature continuous-wave lasing was obtained in the fundamental mode. Furthermore, the switching behavior due to a modal wavelength shift was clearly observed, suggesting the possibility of bistable operation, and so on. © 2008 American Institute of Physics. [DOI: 10.1063/1.2832670]

Photonic crystal (PC) nanolasers could become a key active element in functional integrated photonic chips, because of their small size, low threshold, and strong cavity quantum electrodynamic effects.1-4 Recently, we fabricated the smallest possible PC nanolaser, consisting of only the shift of two lattice points (therefore, termed H0 nanolaser) in a GaInAsP PC slab.5 In this device, the modal field is localized in an area of only 0.17 μm²=0.82(λ/n)², where λ is the modal vacuum wavelength and n is the refractive index of the slab. We achieved room temperature (RT) continuous-wave (cw) operation by optically pumping it at a wavelength of 0.98 μm with a pump spot diameter of 2.5 μm.6 However, this high-frequency pumping with a spot size significantly larger than the modal area leads to unwanted carrier excitation and excess device heating, resulting in strong power saturation and device degradation under the influence of a thermal resistance as high as 10⁶ K/W.7 To improve this situation, we turned to resonant pumping, adjusting the pump wavelength to a high-order cavity mode. To date, the resulting resonant and off-resonant laser characteristics have only been investigated at low temperatures.8 This method effectively pumps only the modal area, thereby suppressing excess heating. In this letter, we demonstrate resonantly pumped RT cw operation of H0 nanolaser. We also observe nonlinear switching behavior in the lasing characteristics, arising from an unusual modal shift.

To fabricate the device, we prepared a GaInAsP–InP epitaxial wafer with a slab active layer consisting of quaternary single-compressively strained quantum well (CS-QW) and separate confinement heterostructure (SCH) layers. The total thickness of the slab was 180 nm. The photoluminescence spectrum of the CS-QW was centered at 1.55 μm. To this wafer, H0 nanocavity surrounded by 20 rows of PC airholes in a triangular lattice was formed by e-beam lithography, HI/Xe inductively coupled plasma etching,9 and HCl selective wet etching, as shown in Fig. 1(a). The lattice constant a, normalized airhole diameter 2r/a, and normalized airhole shift s/a were 580 nm, 0.52, and 0.16, respectively.

In order to characterize the device, pump light was focused to a 2.5 μm spot on the top surface of the nanocavity through an objective lens. The emission from the device was directly collected by a tapered multimode fiber and analyzed by an optical spectrum analyzer (OSA). Figure 1(b) shows the emission spectrum obtained at RT (293 K) by pulsed photopumping at λ=0.98 μm with a duty factor of 0.075%. Two resonant peaks were observed at λ=1537 and 1584 nm. The broad spectral width of these peaks was caused by a combination of thermally induced wavelength chirping10 and the 5 nm resolution of the OSA. Using three-dimensional finite-difference time-domain (FDTD) calculations, we confirmed that the peaks at 1537 and 1584 nm correspond to the dipole and monopole modes, respectively, as illustrated in the inset of Fig. 1(b).

In the resonant photopumping experiment, the dipole and monopole modes were used for pumping and lasing, respectively. Figure 2(a) shows the laser mode intensity as a function of the pump wavelength. As the wavelength was tuned to the dipole mode, the laser mode intensity was dramatically enhanced, due to resonant pumping. Figure 2(b) shows the laser mode intensity versus irradiated power. The inset diagram shows the cw emission spectrum when the

![FIG. 1. (Color online) H0 nanolaser. (a) Scanning electron micrograph of the fabricated device. (b) Resonant modes observed in the photoluminescence spectrum for high-frequency pumping at λ=0.98 μm.](image-url)
Figure 3

Qc approximately 2000 for /H9251/. For resonant pumping at these effects, /H9257/ scattering in the fabricated device. We estimate absorption, out-of-plane radiation loss, and parasitic loss, re-pumped threshold power for resonant pumping than for 0.98

tion efficiency is still much lower than that for high-

addition, be estimated to range from merely 0.12% to 0.20%. But in pumping is preferable. This situation can be dramatically im-

when coupled to mode theory, 14 the absorption efficiency for

t. In the latter case, the absorption efficiency of the pump light was \eta_{abs} = (1-R)(1-e^{-\alpha t})/(1-R\alpha t), where R=30% is the reflectivity at the slab surfaces, \alpha=20 000 cm^{-1} is the absorption coefficient, and t=180 nm (including the SCH layers) is the absorptive layer thickness.11 For resonant pumping at \lambda \approx 1.5 \mu m, on the other hand, \alpha decreases to between 3000 and 5000 cm^{-1}.12,13 and t is only 4 nm for the CS-QW layer, so that \eta_{abs} would be estimated to range from merely 0.12% to 0.20%. But in addition, \eta_{abs} is enhanced by the cavity \eta factor and is reduced by the poor coupling efficiency of the pump light to the cavity mode. The total cavity \eta for the dipole mode is approximately \eta_{total} = \eta_{abs}(Q_c^{-1} + \eta_{ver} + \eta_{par})^{-1}, where the three \eta factors on the right-hand side are determined by interband absorption, out-of-plane radiation loss, and parasitic loss, respec-
tively, caused by free-carrier absorption and by light scattering in the fabricated device. We estimate \eta_{abs} to be 2000 for \alpha=4000 cm^{-1} with an optical confinement factor \Gamma into the CS-QW layer of 2%. In our previous study, we also determined that \eta_{ver} = 2500 and \eta_{par} = 20 000 for the dipole mode, resulting in \eta_{total} = 1050. The coupling efficiency \eta_c was calculated by using the FDTD method to be \eta_c \approx 1%. Ow-
ing to these effects, \eta_{abs} is enhanced by the factor \eta_{total} \eta_c, so that it actually lies between 1.3% and 2.1%. But this absorption efficiency is still much lower than that for high-frequency pumping. Consequently, using the higher irradiated threshold power for resonant pumping than for 0.98 \mu m pumping is preferable. This situation can be dramatically im-

proved by pumping through the input waveguide, as shown schematically in Fig. 3(a). In this case, \eta_{total} = \eta_{abs}(Q_c^{-1} + \eta_{ver} + \eta_{par})^{-1}, where \eta_{abs} is determined by the coupling efficiency \eta between the cavity and the waveguide. According to coupled mode theory,14 the absorption efficiency for pumping through the input waveguide is \eta_{abs} = 4Q_{total}^2/Q_c \eta_{ver}. Figure 3(b) shows the calculated result, where \eta_{ver} is taken to be an unknown variable. Note that \eta_{abs} has a maximum when \eta_{ver} = Q_{total}/(Q_c + \eta_{par})^{-1}. Therefore, when \eta_{ver} is

greater than \eta_{par} \eta_{abs} can exceed 80%. In a standard H0 cavity, \eta_{ver} for a dipole mode is typically 2500. But this value can be enhanced by displacing two neighboring airholes in the H0 cavity, as shown in Fig. 3(c). When the shift \eta_{ver} is larger than 0.08\eta, \eta_{ver} for the dipole mode increases to \eta_{total} while that for the monopole mode remains almost constant.

Finally, we discuss the nonlinear switching behavior ob-

served for another sample, in which the absorption efficiency was larger than that of the previous sample. Figure 4(a) shows the laser mode intensity versus the pump wavelength. A precipitous drop is observed on the long wavelength side of the peak, particularly at high pump levels. Figure 4(b) shows the laser mode intensity as a function of the irradiated power for five different pump wavelengths. When pumped at 1537.5 nm (slightly longer than the dipole mode), the intensity sharply increased at \eta_{irr} = 3.3 mW. As \eta_{irr} increased, the resonant pumping wavelength for the dipole mode was thermally redshifted, as shown in the inset of Fig. 4(b), while the

FIG. 2. (Color online) Laser characteristics obtained by resonantly pumping at \lambda =1536.8 nm. (a) Laser mode intensity vs pump wavelength. (b) Main graph—laser mode intensity vs irradiated power. Inset figure—lasing spectrum when pumped above threshold.

FIG. 4. (Color online) Switching behavior of the pumping wavelength and intensity in the resonant photopumping experiment. (a) Laser mode intensity vs pump wavelength for four different irradiated powers. The arrows indicate the switching wavelength. (b) Laser mode intensity vs irradiated power for five different pumping wavelengths. The inset shows the shift in the wavelength and intensity of the dipole and monopole modes, respectively.

FIG. 3. (Color online) Resonant photopumping through an input waveguide. (a) Schematic of the H0 nanolaser integrated with an input waveguide. (b) Plot of \eta_{abs} vs \eta_{ver}. Here, \eta_{ver} and \eta_{par} are assumed to be 2000 and 20 000, respectively, while \eta_{ver} is an unknown variable. (c) Graph of \eta_{ver} for the two cavity modes calculated with the airhole shift \eta_{ver} shown in the inset.
laser intensity of the monopole mode sharply increased. The spectral broadening shown in Fig. 4(a) can be explained by the thermal redshift and by the locking of the resonance with the upward wavelength sweep. Such characteristics suggest the possibility of bistable switching with an extinction ratio of 12 dB. This value is higher than that for the bistability observed in passive PC cavities. It is attributed to the active operation of the laser, where switching between spontaneous and stimulated emission occurs with a change in the absorption efficiency.

In conclusion, we have demonstrated RT cw operation of a PC nanolaser by resonant optical pumping. The intensity of the monopole mode, with a modal volume of merely 0.019 $\mu$m$^3$, was enhanced by up to 35 dB above the background level when the pump wavelength was fixed at that of the dipole mode. Its high threshold is due to the low pump efficiency, but can be reduced by in-plane coupling of the pump light through the waveguide. We also observed thermal nonlinear switching with an extinction ratio of 12 dB, demonstrating the possibility of bistable operation. We have already realized the integration of the active nanolaser with passive waveguides using a butt-joint regrowth technique. It allows resonant pumping through the input waveguide and light extraction through the output waveguide. This will enable various functionalities such as an optical 2R (reamplifying and reshaping) device or a wavelength converter.

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